SN74LV8T373-EP Enhanced Product Octal Transparent D-Type Latches with 3-State Outputs

1 Features

- Wide operating range of 1.65V to 5.5V
- 5.5V tolerant input pins
- Single-supply voltage translator (refer to *LVxT Enhanced Input Voltage*):
  - Up translation:
    - 1.2V to 1.8V
    - 1.5V to 2.5V
    - 1.8V to 3.3V
    - 3.3V to 5.0V
  - Down translation:
    - 5.0V, 3.3V, 2.5V to 1.8V
    - 5.0V, 3.3V to 2.5V
    - 5.0V to 3.3V
- Up to 150Mbps with 5V or 3.3V V_{CC}
- Supports standard function pinout
- Latch-up performance exceeds 250mA per JESD 17
- Supports defense and aerospace applications:
  - Controlled baseline
  - One assembly and test site
  - One fabrication site
  - Extended product life cycle
  - Product traceability

2 Applications

- Drive an indicator LED
- Redrive a digital signal
- Drive a transmission line
- Hold a signal during controller reset

3 Description

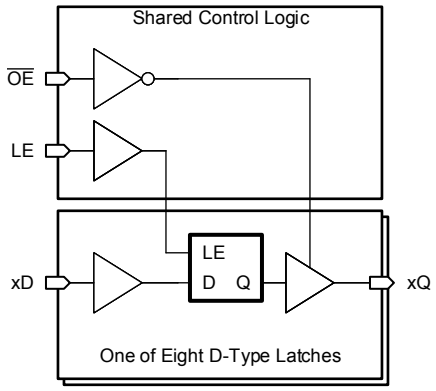
The SN74LV8T373-EP device is an octal transparent D-type latch designed for 2V to 5.5V V_{CC} operation.

The input is designed with a reduced threshold circuit to support up translation when the supply voltage is larger than the input voltage. Additionally, the 5V tolerant input pins enable down translation when the input voltage is larger than the supply voltage. The output level is always referenced to the supply voltage (V_{CC}) and supports 1.8V, 2.5V, 3.3V, and 5V CMOS levels.

Package Information

PART NUMBER	PACKAGE(1)	PACKAGE SIZE(2)	BODY SIZE (NOM)(3)
SN74LV8T373-EP	PW (TSSOP, 20)	6.5mm × 6.4mm	6.5mm × 4.4mm

(1) For more information, see Mechanical, Packaging, and Orderable Information.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.
(3) The body size (length × width) is a nominal value and does not include pins.



Simplified Logic Diagram (Positive Logic)

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Pin Configuration and Functions

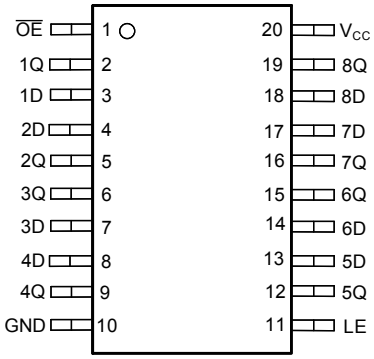

Figure 4-1. PW Package, 20-Pin TSSOP (Top View)

Table 4-1. Pin Functions

PIN			TYPE	DESCRIPTION
NO.		Name		
1		$\overline{OE}$	I	Output Enable
2		1Q	O	1Q Output
3		1D	I	1D Input
4		2D	I	2D Input
5		2Q	O	2Q Output
6		3Q	O	3Q Output
7		3D	I	3D Input
8		4D	I	4D Input
9		4Q	O	4Q Output
10		GND	—	Ground Pin
11		LE	I	Latch Enable
12		5Q	O	5Q Output
13		5D	I	5D Input
14		6D	I	6D Input
15		6Q	O	6Q Output
16		7Q	O	7Q Output
17		7D	I	7D Input
18		8D	I	8D Input
19		8Q	O	8Q Output
20		V_{CC}	—	Power Pin

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5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		–0.5	7	V
V_I	Input voltage range(2)		–0.5	7	V
V_O	Voltage range applied to any output in the high-impedance or power-off state(2)		–0.5	7	V
V_O	Output voltage range(2)		–0.5	V_{CC} + 0.5	V
I_{IK}	Input clamp current	V_I < -0.5V		-20	mA
I_{OK}	Output clamp current	V_O < -0.5V or V_O > V_{CC} + 0.5V		±20	mA
I_O	Continuous output current	V_O = 0 to V_{CC}		±25	mA
	Continuous output current through V_{CC} or GND			±75	mA
T_{stg}	Storage temperature		-65	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If briefly operating outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002(2)	±1000	

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

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5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

Spec	Description	Condition	MIN	MAX	UNIT
V_{CC}	Supply voltage		1.65	5.5	V
V_I	Input voltage		0	5.5	V
V_O	Output voltage		0	V_{CC}	V
V_{IH}	High-level input voltage	V_{CC} = 1.65V to 2V	1.1		V
		V_{CC} = 2.25V to 2.75V	1.28		
		V_{CC} = 3V to 3.6V	1.45		
		V_{CC} = 4.5V to 5.5V	2		
V_{IL}	Low-Level input voltage	V_{CC} = 1.65V to 2V		0.5	V
		V_{CC} = 2.25V to 2.75V		0.65	
		V_{CC} = 3V to 3.6V		0.75	
		V_{CC} = 4.5V to 5.5V		0.85	
I_O	Output current	V_{CC} = 1.6V to 2V		±3	mA
		V_{CC} = 2.25V to 2.75V		±7	
		V_{CC} = 3.3V to 5.0V		±15	
I_O	Output Current	V_{CC} = 4.5V to 5.5V		±25	mA
Δt/Δv	Input transition rise or fall rate	V_{CC} = 1.6V to 5.0V		20	ns/V
T_A	Operating free-air temperature		-55	125	°C

5.4 Thermal Information

THERMAL METRIC[1]		SN74LV8T373-EP	UNIT
		PW (TSSOP)	
		20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	122.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	64.8	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	73.3	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	19.0	°C/W
Y_{JB}	Junction-to-board characterization parameter	73.0	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

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5.5 Electrical Characteristics

over operating free-air temperature range; typical ratings measured at T_A = 25°C (unless otherwise noted).

PARAMETER	TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
V_{OH}	I_{OH} = -50 uA	1.65V to 5.5V	V_{CC}-0.1			V
	I_{OH} = -2 mA	1.65V to 2V	1.21	1.7(1)		
	I_{OH} = -3 mA	2.25V to 2.75V	1.93	2.4(1)		
	I_{OH} = -5.5 mA	3V to 3.6V	2.49	3.08(1)		
	I_{OH} = -8 mA	4.5V to 5.5V	3.95	4.65(1)		
V_{OL}	I_{OL}= 50 µA	1.65V to 5.5V			0.1	V
	I_{OL} = 2 mA	1.65V to 2V		0.1(1)	0.25	
	I_{OL} = 3 mA	2.25V to 2.75V		0.1(1)	0.2	
	I_{OL} = 5.5 mA	3V to 3.6V		0.2(1)	0.25	
	I_{OL}= 8 mA	4.5V to 5.5V		0.3(1)	0.35	
I_I	V_I = 0 V or V_{CC}	0V to 5.5V			±1	µA
I_{CC}	V_I = V_{CC} or GND, I_O = 0	1.65V to 5.5V			10	µA
ΔI_{CC}	One input at 0.3 V or 3.4 V, other inputs at 0 or V_{CC}, I_O = 0	5.5V			1.5	mA
	One input at 0.3 V or 1.1 V, other inputs at 0 or V_{CC}, I_O = 0	1.8V			20	µA
C_I	V_I = V_{CC} or GND	5V		2	10	pF
C_O	V_O = V_{CC} or GND	5V		5		pF
I_{OZ}	V_O = V_{CC} or GND and V_{CC} = 5.5 V	5.5V			±2.5	µA
C_{PD} (2) (3)	C_L = 50 pF, F = 10 MHz	1.65V to 5.5V		105		pF

(1) Typical value at nearest nominal voltage (1.8V, 2.5V, 3.3V, and 5V)
(2) C_{PD} is used to determine the dynamic power consumption, per channel.
(3) P_D= V_{CC} ^{2}xF_Ix(C_{PD}+ C_L) where F_I= input frequency, C_L= output load capacitance, V_{CC}= supply voltage.

5.6 Timing Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	DESCRIPTION	CONDITION	V_{CC}	-55°C to 125°C		UNIT
				MIN	MAX	
t_H	Hold time	Data after LE↓	1.8V	2		ns
t_{SU}	Setup time	Data before LE↓	1.8V	5		ns
t_W	Pulse duration	LE high	1.8V	6.5		ns
t_H	Hold time	Data after LE↓	2.5V	2		ns
t_{SU}	Setup time	Data before LE↓	2.5V	5		ns
t_W	Pulse duration	LE high	2.5V	6.5		ns
t_H	Hold time	Data after LE↓	3.3V	1.5		ns
t_{SU}	Setup time	Data before LE↓	3.3V	3.5		ns
t_W	Pulse duration	LE high	3.3V	5		ns
t_H	Hold time	Data after LE↓	5V	1.5		ns
t_{SU}	Setup time	Data before LE↓	5V	3.5		ns
t_W	Pulse duration	LE high	5V	5		ns

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5.7 Switching Characteristics

over operating free-air temperature range; typical values measured at T_A = 25°C (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	Load Capacitance	V_{CC}	-55°C to 125°C			UNIT
					MIN	TYP	MAX	
t_{PHL}	D	Q	C_L = 15pF	1.8V	1		39.7	ns
t_{PHL}	D	Q	C_L = 50pF	1.8V	1		44.5	ns
t_{PHL}	LE	Q	C_L = 15pF	1.8V	1		33.1	ns
t_{PHL}	LE	Q	C_L = 50pF	1.8V	1		38.2	ns
t_{PHZ}	$\overline{OE}$	Q	C_L = 15pF	1.8V	1		25.6	ns
t_{PHZ}	$\overline{OE}$	Q	C_L = 50pF	1.8V	1		32.3	ns
t_{PLH}	D	Q	C_L = 15pF	1.8V	1		33.3	ns
t_{PLH}	D	Q	C_L = 50pF	1.8V	1		37.3	ns
t_{PHL}	LE	Q	C_L = 15pF	1.8V	1		27.8	ns
t_{PHL}	LE	Q	C_L = 50pF	1.8V	1		31.7	ns
t_{PLZ}	$\overline{OE}$	Q	C_L = 15pF	1.8V	1		22.6	ns
t_{PLZ}	$\overline{OE}$	Q	C_L = 50pF	1.8V	1		29.6	ns
t_{PZH}	$\overline{OE}$	Q	C_L = 15pF	1.8V	1		28.4	ns
t_{PZH}	$\overline{OE}$	Q	C_L = 50pF	1.8V	1		32.4	ns
t_{PZL}	$\overline{OE}$	Q	C_L = 15pF	1.8V	1		29.5	ns
t_{PZL}	$\overline{OE}$	Q	C_L = 50pF	1.8V	1		34.1	ns
t_{PHL}	D	Q	C_L = 15pF	2.5V	1		23.3	ns
t_{PHL}	D	Q	C_L = 50pF	2.5V	1		26.6	ns
t_{PHL}	LE	Q	C_L = 15pF	2.5V	1		18.7	ns
t_{PHL}	LE	Q	C_L = 50pF	2.5V	1		22.9	ns
t_{PHZ}	$\overline{OE}$	Q	C_L = 15pF	2.5V	1		15.4	ns
t_{PHZ}	$\overline{OE}$	Q	C_L = 50pF	2.5V	1		19.8	ns
t_{PLH}	D	Q	C_L = 15pF	2.5V	1		19.1	ns
t_{PLH}	D	Q	C_L = 50pF	2.5V	1		21.7	ns
t_{PHL}	LE	Q	C_L = 15pF	2.5V	1		15.3	ns
t_{PHL}	LE	Q	C_L = 50pF	2.5V	1		17.9	ns
t_{PLZ}	$\overline{OE}$	Q	C_L = 15pF	2.5V	1		13.6	ns
t_{PLZ}	$\overline{OE}$	Q	C_L = 50pF	2.5V	1		18.3	ns
t_{PZH}	$\overline{OE}$	Q	C_L = 15pF	2.5V	1		17.7	ns
t_{PZH}	$\overline{OE}$	Q	C_L = 50pF	2.5V	1		19.7	ns
t_{PZL}	$\overline{OE}$	Q	C_L = 15pF	2.5V	1		17.3	ns
t_{PZL}	$\overline{OE}$	Q	C_L = 50pF	2.5V	1		21.1	ns
t_{PHL}	D	Q	C_L = 15pF	3.3V	1		16.6	ns
t_{PHL}	D	Q	C_L = 50pF	3.3V	1		19.2	ns
t_{PHL}	LE	Q	C_L = 15pF	3.3V	1		13.8	ns
t_{PHL}	LE	Q	C_L = 50pF	3.3V	1		16.5	ns
t_{PHZ}	$\overline{OE}$	Q	C_L = 15pF	3.3V	1		11	ns
t_{PHZ}	$\overline{OE}$	Q	C_L = 50pF	3.3V	1		14.5	ns
t_{PLH}	D	Q	C_L = 15pF	3.3V	1		13.4	ns
t_{PLH}	D	Q	C_L = 50pF	3.3V	1		15.5	ns
t_{PHL}	LE	Q	C_L = 15pF	3.3V	1		11.9	ns
t_{PHL}	LE	Q	C_L = 50pF	3.3V	1		14	ns
t_{PLZ}	$\overline{OE}$	Q	C_L = 15pF	3.3V	1		10	ns

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over operating free-air temperature range; typical values measured at T_A = 25°C (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	Load Capacitance	V_{CC}	-55°C to 125°C			UNIT
					MIN	TYP	MAX	
t_{PLZ}	$\overline{OE}$	Q	C_L = 50pF	3.3V	1		13.4	ns
t_{PZH}	$\overline{OE}$	Q	C_L = 15pF	3.3V	1		12.8	ns
t_{PZH}	$\overline{OE}$	Q	C_L = 50pF	3.3V	1		14.5	ns
t_{PZL}	$\overline{OE}$	Q	C_L = 15pF	3.3V	1		13.1	ns
t_{PZL}	$\overline{OE}$	Q	C_L = 50pF	3.3V	1		16	ns
t_{PHL}	D	Q	C_L = 15pF	5V	1		11.2	ns
t_{PHL}	D	Q	C_L = 50pF	5V	1		13.2	ns
t_{PHL}	LE	Q	C_L = 15pF	5V	1		10.1	ns
t_{PHL}	LE	Q	C_L = 50pF	5V	1		12.3	ns
t_{PHZ}	$\overline{OE}$	Q	C_L = 15pF	5V	1		8.3	ns
t_{PHZ}	$\overline{OE}$	Q	C_L = 50pF	5V	1		10.4	ns
t_{PLH}	D	Q	C_L = 15pF	5V	1		9.8	ns
t_{PLH}	D	Q	C_L = 50pF	5V	1		11.4	ns
t_{PHL}	LE	Q	C_L = 15pF	5V	1		8.8	ns
t_{PHL}	LE	Q	C_L = 50pF	5V	1		10.7	ns
t_{PLZ}	$\overline{OE}$	Q	C_L = 15pF	5V	1		7.4	ns
t_{PLZ}	$\overline{OE}$	Q	C_L = 50pF	5V	1		9.7	ns
t_{PZH}	$\overline{OE}$	Q	C_L = 15pF	5V	1		8.8	ns
t_{PZH}	$\overline{OE}$	Q	C_L = 50pF	5V	1		10.7	ns
t_{PZL}	$\overline{OE}$	Q	C_L = 15pF	5V	1		9.1	ns
t_{PZL}	$\overline{OE}$	Q	C_L = 50pF	5V	1		11.3	ns

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5.8 Typical Characteristics

T_A = 25°C (unless otherwise noted)

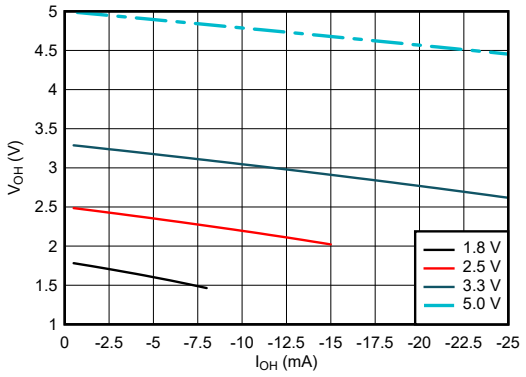

Figure 5-1. Output Voltage vs Current in HIGH State

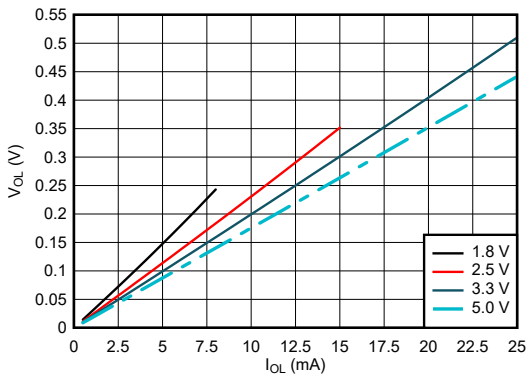

Figure 5-2. Output Voltage vs Current in LOW State

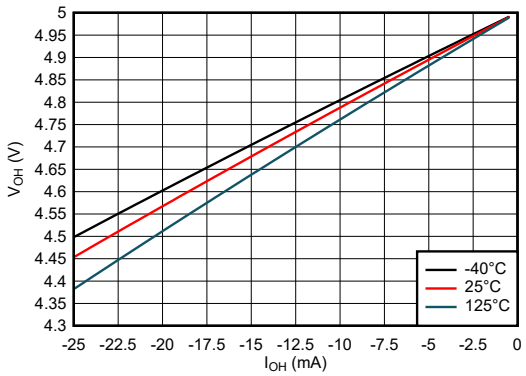

Figure 5-3. Output Voltage vs Current in HIGH State; 5V Supply

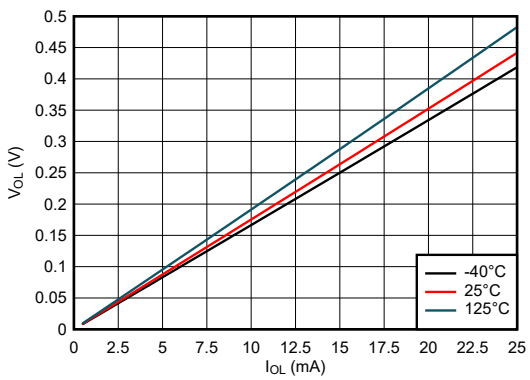

Figure 5-4. Output Voltage vs Current in LOW State; 5V Supply

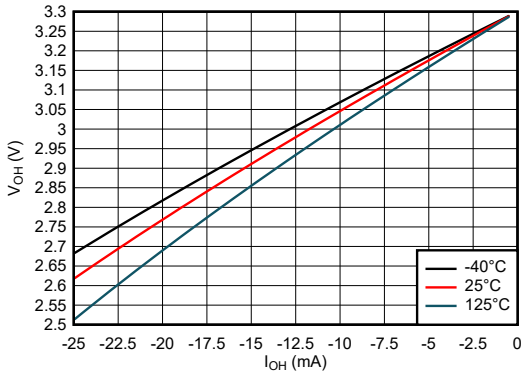

Figure 5-5. Output Voltage vs Current in HIGH State; 3.3V Supply

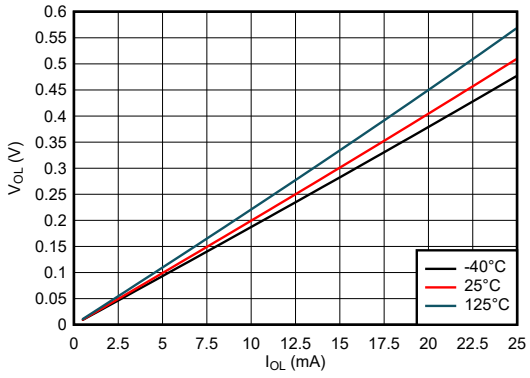

Figure 5-6. Output Voltage vs Current in LOW State; 3.3V Supply

5.8 Typical Characteristics (continued)

T_A = 25°C (unless otherwise noted)

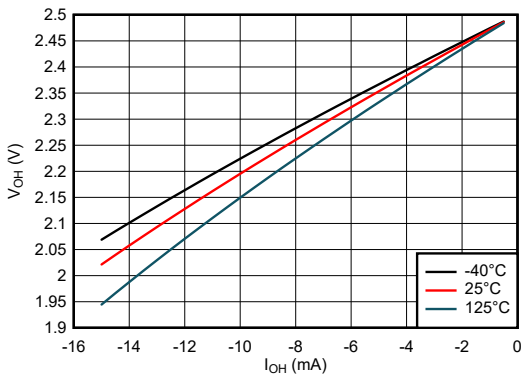

Figure 5-7. Output Voltage vs Current in HIGH State; 2.5V Supply

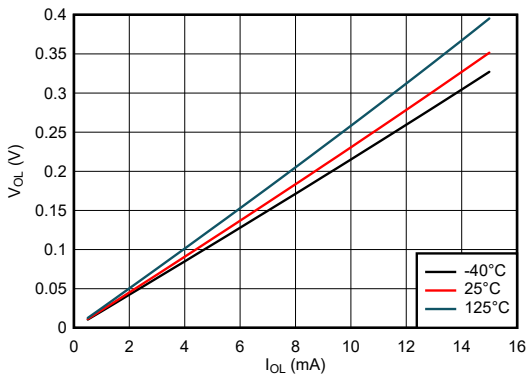

Figure 5-8. Output Voltage vs Current in LOW State; 2.5V Supply

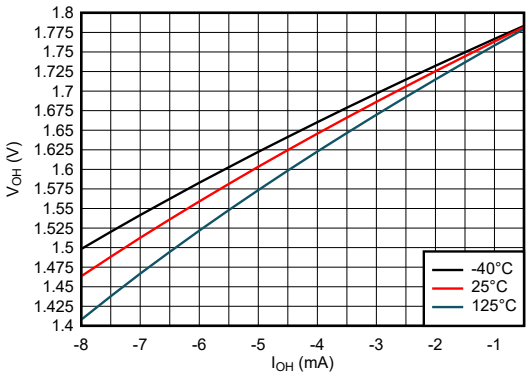

Figure 5-9. Output Voltage vs Current in HIGH State; 1.8V Supply

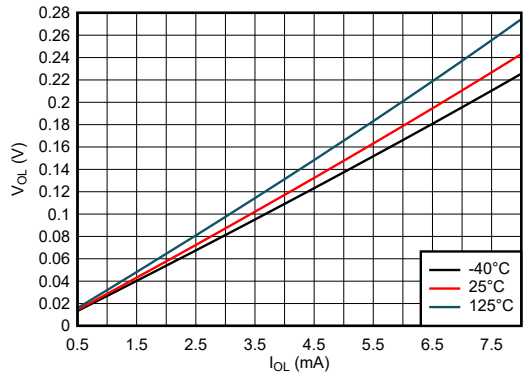

Figure 5-10. Output Voltage vs Current in LOW State; 1.8V Supply

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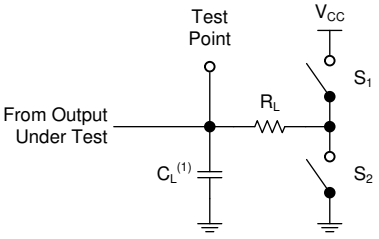
6 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily for the examples listed in the following table. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1MHz, Z_O = 50Ω, t_t < 2.5ns.

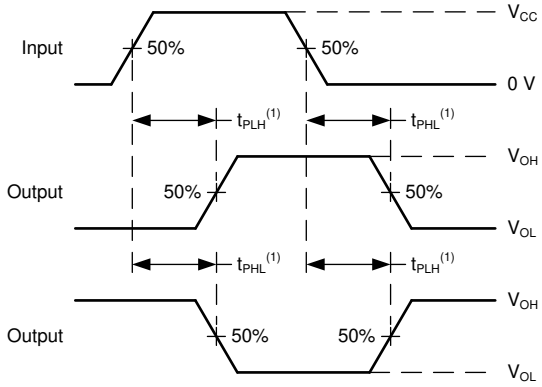
The outputs are measured individually with one input transition per measurement.

TEST	S1	S2	R_L	C_L	ΔV	V_{CC}
t_{PLH}, t_{PHL}	OPEN	OPEN	—	15pF, 50pF	—	ALL
t_{PLZ}, t_{PZL}	CLOSED	OPEN	1kΩ	15pF, 50pF	0.15V	≤ 2.5V
t_{PHZ}, t_{PZH}	OPEN	CLOSED	1kΩ	15pF, 50pF	0.15V	≤ 2.5V
t_{PLZ}, t_{PZL}	CLOSED	OPEN	1kΩ	15pF, 50pF	0.3V	> 2.5V
t_{PHZ}, t_{PZH}	OPEN	CLOSED	1kΩ	15pF, 50pF	0.3V	> 2.5V



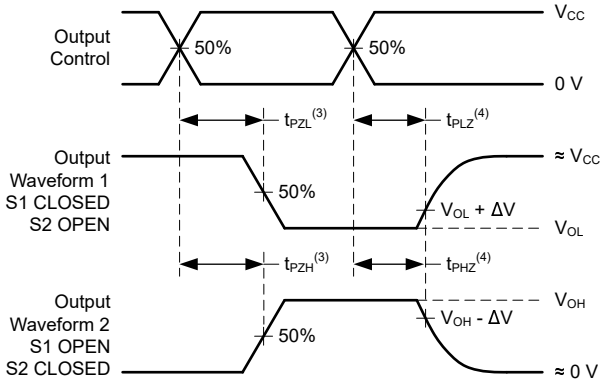
(1) C_L includes probe and test-fixture capacitance.

Figure 6-1. Load Circuit for 3-State Outputs



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd}.

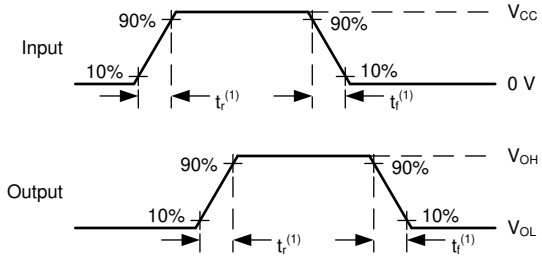
Figure 6-2. Voltage Waveforms Propagation Delays



(3) The greater between t_{PZL} and t_{PZH} is the same as t_{en}.

(4) The greater between t_{PLZ} and t_{PHZ} is the same as t_{dis}.

Figure 6-3. Voltage Waveforms Propagation Delays



(1) The greater between t_r and t_f is the same as t_t.

Figure 6-4. Voltage Waveforms, Input and Output Transition Times

7 Detailed Description

7.1 Overview

The SN74LV8T373-EP contains eight D-type latches. All channels share a latch enable (LE) and output enable ($\overline{OE}$) input.

When the latch is enabled (LE is high), data is allowed to pass through from the D inputs to the Q outputs.

When the latch is disabled (LE is low), the Q outputs hold the last state they had regardless of changes at the D inputs.

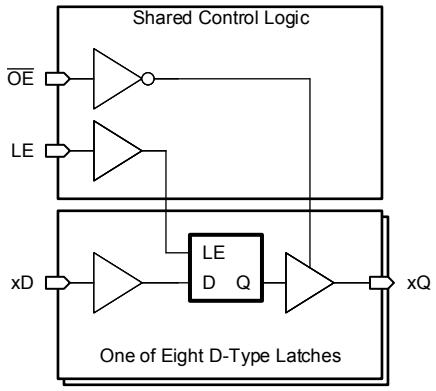
If the latch enable (LE) input is held low during startup, the output state of all channels is unknown until the latch enable (LE) input is driven high with valid input signals at all data (D) inputs.

When the outputs are enabled ($\overline{OE}$ is low), the outputs are actively driving low or high.

When the outputs are disabled ($\overline{OE}$ is high), the outputs are set into the high-impedance state.

The active low output enable ($\overline{OE}$) does not have any impact on the stored state in the latches.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Balanced CMOS 3-State Outputs

This device includes balanced CMOS 3-state outputs. Driving high, driving low, and high impedance are the three states that these outputs can be in. The term *balanced* indicates that the device can sink and source similar currents. The drive capability of this device may create fast edges into light loads, so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device can drive larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to overcurrent. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

When placed into the high-impedance state, the output will neither source nor sink current, with the exception of minor leakage current as defined in the *Electrical Characteristics* table. In the high-impedance state, the output voltage is not controlled by the device and is dependent on external factors. If no other drivers are connected to the node, then this is known as a floating node and the voltage is unknown. A pull-up or pull-down resistor can be connected to the output to provide a known voltage at the output while it is in the high-impedance state. The value of the resistor will depend on multiple factors, including parasitic capacitance and power consumption limitations. Typically, a 10kΩ resistor can be used to meet these requirements.

Unused 3-state CMOS outputs should be left disconnected.

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7.3.2 LVxT Enhanced Input Voltage

The SN74LV8T373-EP belongs to TI's LVxT family of logic devices with integrated voltage level translation. This family of devices was designed with reduced input voltage thresholds to support up-translation, and inputs tolerant of signals with up to 5.5V levels to support down-translation. For proper functionality, input signals must remain at or above the specified $V_{IH(MIN)}$ level for a HIGH input state, and at or below the specified $V_{IL(MAX)}$ for a LOW input state. Figure 7-1 shows the typical V_{IH} and V_{IL} levels for the LVxT family of devices, as well as the voltage levels for standard CMOS devices for comparison.

The inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using Ohm's law (R = V ÷ I).

Input signals must transition between valid logic states quickly, as defined by the input transition rate in the *Recommended Operating Conditions* table. Failing to meet this specification will result in excessive power consumption and could cause oscillations. More details can be found in the *Implications of Slow or Floating CMOS Inputs* application report.

Do not leave inputs floating at any time during operation. Unused inputs must be terminated at a valid high or low voltage level. If a system will not be actively driving an input at all times, then a pull-up or pull-down resistor can be added to provide a valid input voltage during these times. The resistor value will depend on multiple factors; however, a 10kΩ resistor is recommended and will typically meet all requirements.

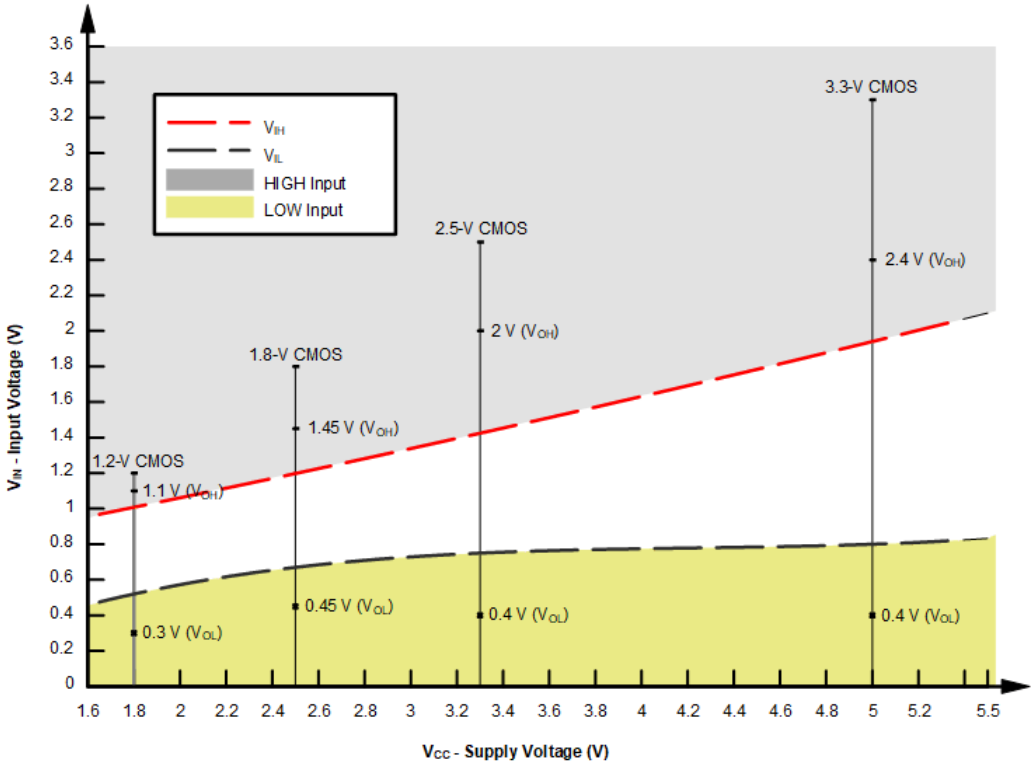

Figure 7-1. LVxT Input Voltage Levels

7.3.2.1 Up Translation

Input signals can be up translated using the SN74LV8T373-EP. The voltage applied at V_{CC} will determine the output voltage and the input thresholds as described in the *Recommended Operating Conditions* and *Electrical Characteristics* tables. When connected to a high-impedance input, the output voltage will be approximately V_{CC} in the HIGH state, and 0V in the LOW state.

The inputs have reduced thresholds that allow for input HIGH state levels, which are much lower than standard values. For example, standard CMOS inputs for a device operating at a 5V supply will have a $V_{IH(MIN)}$ of 3.5V. For the SN74LV8T373-EP, $V_{IH(MIN)}$ with a 5V supply is only 2V, which would allow for up-translation from a typical 2.5V to 5V signals.

Ensure that the input signals in the HIGH state are above $V_{IH(MIN)}$ and input signals in the LOW state are lower than $V_{IL(MAX)}$ as shown in Figure 7-2.

Up Translation Combinations are as follows:

- 1.8V V_{CC} – Inputs from 1.2V
- 2.5V V_{CC} – Inputs from 1.8V
- 3.3V V_{CC} – Inputs from 1.8V and 2.5V
- 5.0V V_{CC} – Inputs from 2.5V and 3.3V

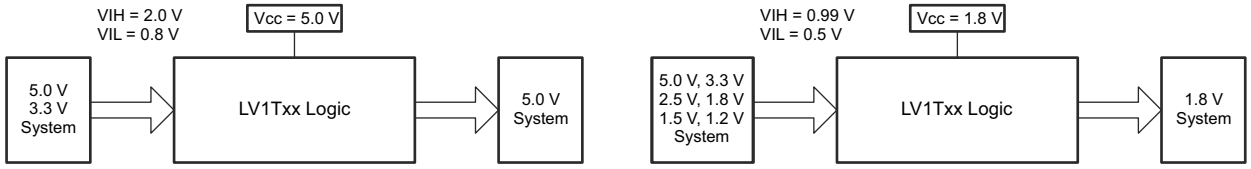

Figure 7-2. LVxT Up and Down Translation Example

7.3.2.2 Down Translation

Signals can be translated down using the SN74LV8T373-EP. The voltage applied at the V_{CC} will determine the output voltage and the input thresholds as described in the *Recommended Operating Conditions* and *Electrical Characteristics* tables.

When connected to a high-impedance input, the output voltage will be approximately V_{CC} in the HIGH state, and 0V in the LOW state. Ensure that the input signals in the HIGH state are between $V_{IH(MIN)}$ and 5.5V, and input signals in the LOW state are lower than $V_{IL(MAX)}$ as shown in Figure 7-1.

For example, standard CMOS inputs for devices operating at 5.0V, 3.3V or 2.5V can be down-translated to match 1.8V CMOS signals when operating from 1.8V V_{CC}. See Figure 7-2.

Down Translation Combinations are as follows:

- 1.8V V_{CC} – Inputs from 2.5V, 3.3V, and 5.0V
- 2.5V V_{CC} – Inputs from 3.3V and 5.0V
- 3.3V V_{CC} – Inputs from 5.0V

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7.4 Device Functional Modes

Table 7-1. Function Table

INPUTS[1]			OUTPUT[2]
$\overline{OE}$	LE	D	Q
L	H	L	L
L	H	H	H
L	L	X	Q_0 [3]
H	X	X	Z

(1) L = input low, H = input high, ↑ = input transitioning from low to high, ↓ = input transitioning from high to low, X = don't care
(2) L = output low, H = output high, Q_0 = previous state, Z = high impedance
(3) At startup, Q_0 is unknown

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8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

In this application, the SN74LV8T373-EP is used to control an 8-bit data bus.

Outputs can be held in the high-impedance state, held in the last known state, or change together with the data inputs, depending on the control inputs at LE and $\overline{OE}$ coming from the bus controller.

8.2 Typical Application

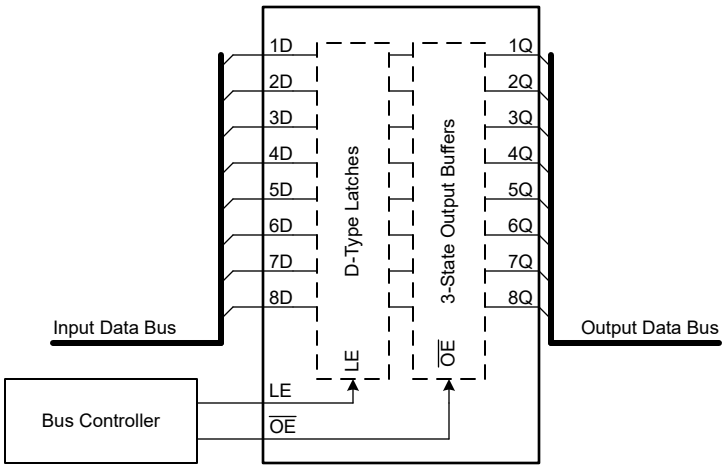

Figure 8-1. Typical Application Block Diagram

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8.2.1 Design Requirements

8.2.1.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the device's electrical characteristics of the device as described in the *Electrical Characteristics* section.

The positive voltage supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74LV8T373-EP plus the maximum static supply current, I_{CC}, listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only source as much current that is provided by the positive supply source. Ensure the maximum total current through V_{CC} listed in the *Absolute Maximum Ratings* is not exceeded.

The ground must be capable of sinking current equal to the total current to be sunk by all outputs of the SN74LV8T373-EP plus the maximum supply current, I_{CC}, listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only sink as much current that can be sunk into its ground connection. Ensure the maximum total current through GND listed in the *Absolute Maximum Ratings* is not exceeded.

The SN74LV8T373-EP can drive a load with a total capacitance less than or equal to 50pF while still meeting all of the data sheet specifications. Larger capacitive loads can be applied; however, it is not recommended to exceed 50pF.

The SN74LV8T373-EP can drive a load with total resistance described by $R_L \geq V_O / I_O$, with the output voltage and current defined in the *Electrical Characteristics* table with V_{OH} and V_{OL}. When outputting in the HIGH state, the output voltage in the equation is defined as the difference between the measured output voltage and the supply voltage at the V_{CC} pin.

Total power consumption can be calculated using the information provided in *CMOS Power Consumption and Cpd Calculation*.

Thermal increase can be calculated using the information provided in *Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices*.

CAUTION

The maximum junction temperature, $T_{J(max)}$ listed in the *Absolute Maximum Ratings*, is an additional limitation to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

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8.2.1.2 Input Considerations

Input signals must cross to be considered a logic LOW, and to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either V_{CC} or ground. The unused inputs can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input will be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The drive current of the controller, leakage current into the SN74LV8T373-EP (as specified in the *Electrical Characteristics*), and the desired input transition rate limits the resistor size. A 10kΩ resistor value is often used due to these factors.

Refer to the *Feature Description* section for additional information regarding the inputs for this device.

8.2.1.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the V_{OH} specification in the *Electrical Characteristics*. The ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the V_{OL} specification in the *Electrical Characteristics*.

Push-pull outputs that could be in opposite states, even for a very short time period, should never be connected directly together. This can cause excessive current and damage to the device.

Two channels within the same device with the same input signals can be connected in parallel for additional output drive strength.

Unused outputs can be left floating. Do not connect outputs directly to V_{CC} or ground.

Refer to the *Feature Description* section for additional information regarding the outputs for this device.

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8.2.2 Detailed Design Procedure

1. Add a decoupling capacitor from V_{CC} to GND. The capacitor needs to be placed physically close to the device and electrically close to both the V_{CC} and GND pins. An example layout is shown in the *Layout* section.
2. Ensure the capacitive load at the output is ≤ 50pF. This is not a hard limit; by design, however, it will optimize performance. This can be accomplished by providing short, appropriately sized traces from the SN74LV8T373-EP to one or more of the receiving devices.
3. Ensure the resistive load at the output is larger than (V_{CC} / $I_{O(max)}$)Ω. Doing this will prevent the maximum output current from the *Absolute Maximum Ratings* from being violated. Most CMOS inputs have a resistive load measured in MΩ; much larger than the minimum calculated previously.
4. Thermal issues are rarely a concern for logic gates; the power consumption and thermal increase, however, can be calculated using the steps provided in the application report, *CMOS Power Consumption and Cpd Calculation*.

8.2.3 Application Curves

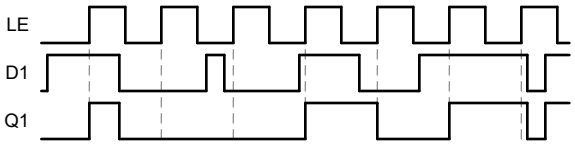

Figure 8-2. Application Timing Diagram

8.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1µF and 1µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

8.4 Layout

8.4.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices, inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC}, whichever makes more sense for the logic function or is more convenient.

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8.4.2 Layout Example

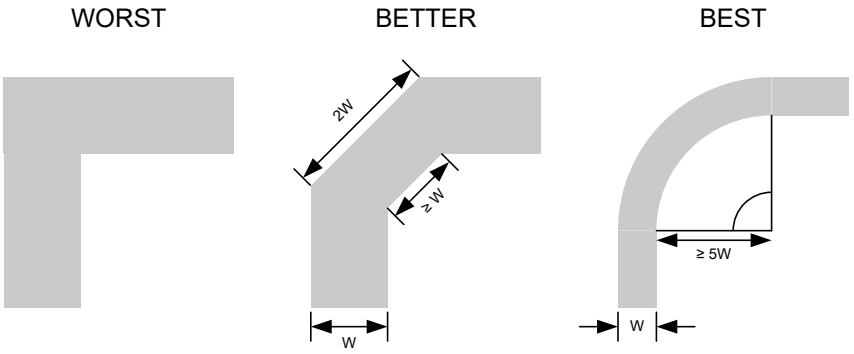

Figure 8-3. Example trace corners for improved signal integrity

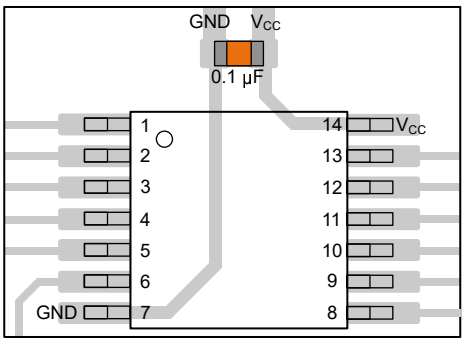

Figure 8-4. Example bypass capacitor placement for TSSOP and similar packages

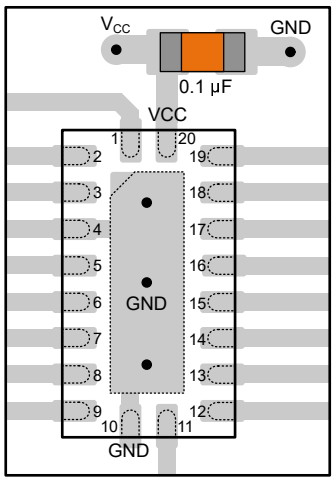

Figure 8-5. Example bypass capacitor placement for WQFN and similar packages

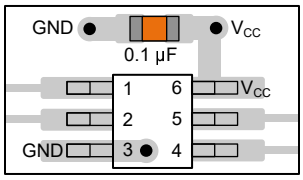

Figure 8-6. Example bypass capacitor placement for SOT, SC70 and similar packages

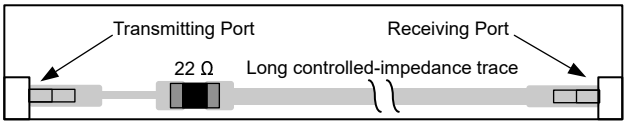

Figure 8-7. Example damping resistor placement for improved signal integrity

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9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, *CMOS Power Consumption and C_{pd} Calculation* application report
- Texas Instruments, *Designing With Logic* application report

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

9.5 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision * (August 2024) to Revision A (October 2024)	Page
• Updated data sheet status from Advance Information to Production Data	1

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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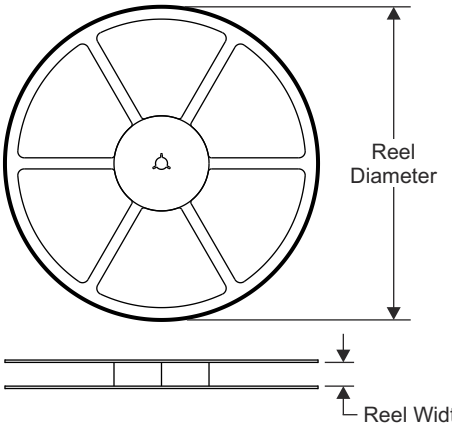
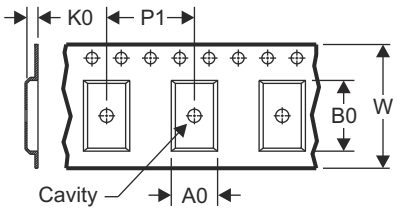
11.1 Tape and Reel Information

REEL DIMENSIONS

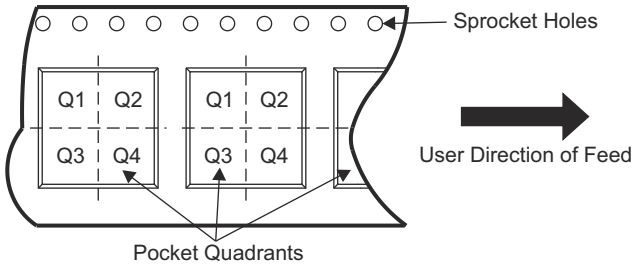


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
1I8T373MPWREP	TSSOP	PW	20	2000	330.0	16.4	6.95	7.00	1.4	8.0	12.0	Q1

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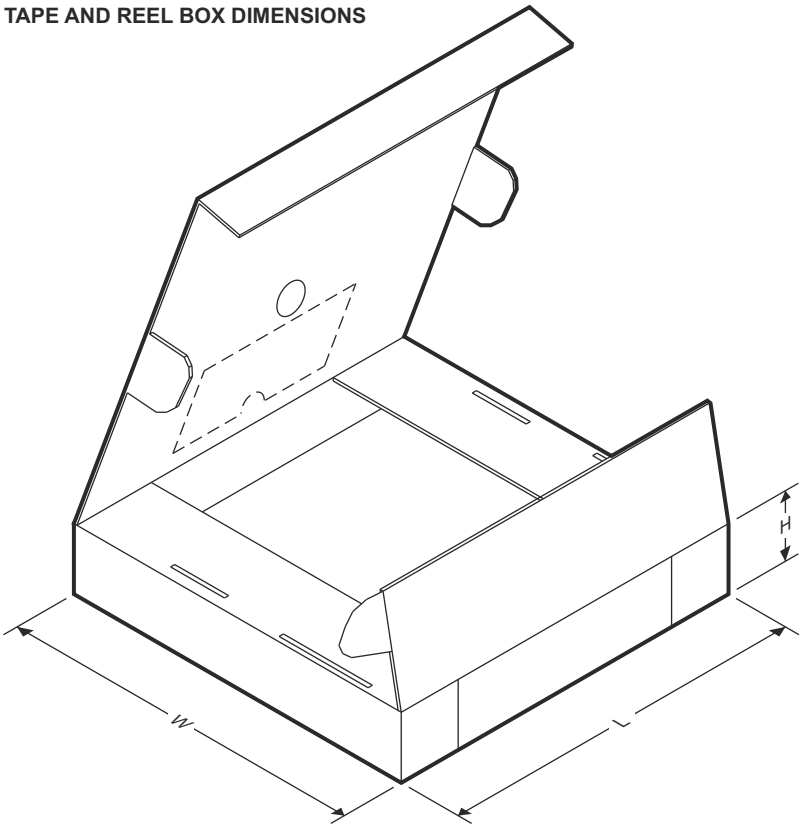
TAPE AND REEL BOX DIMENSIONS



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
1I8T373MPWREP	TSSOP	PW	20	2000	367.0	367.0	38.0

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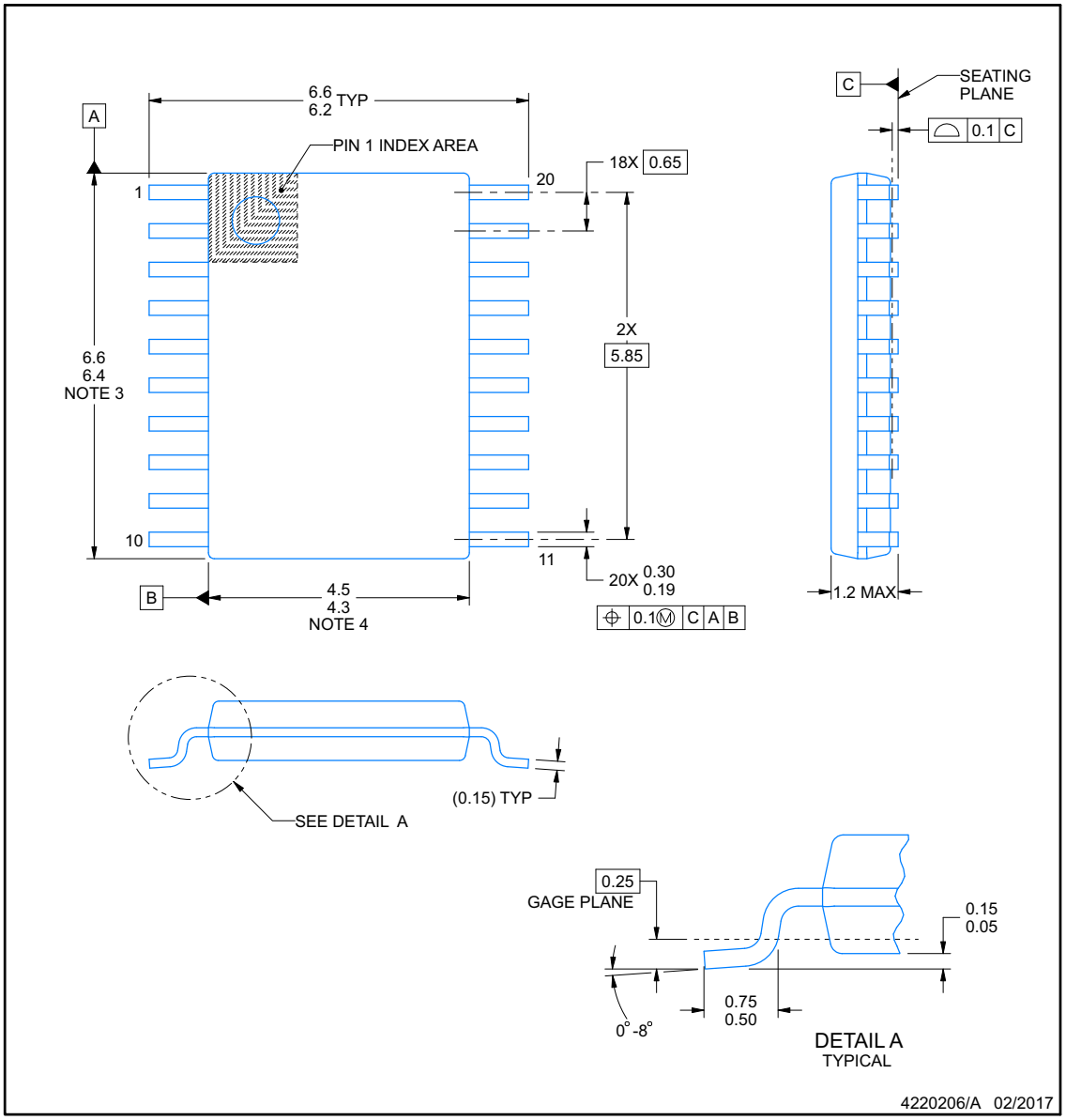
11.2 Mechanical Data

PW0020A

PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

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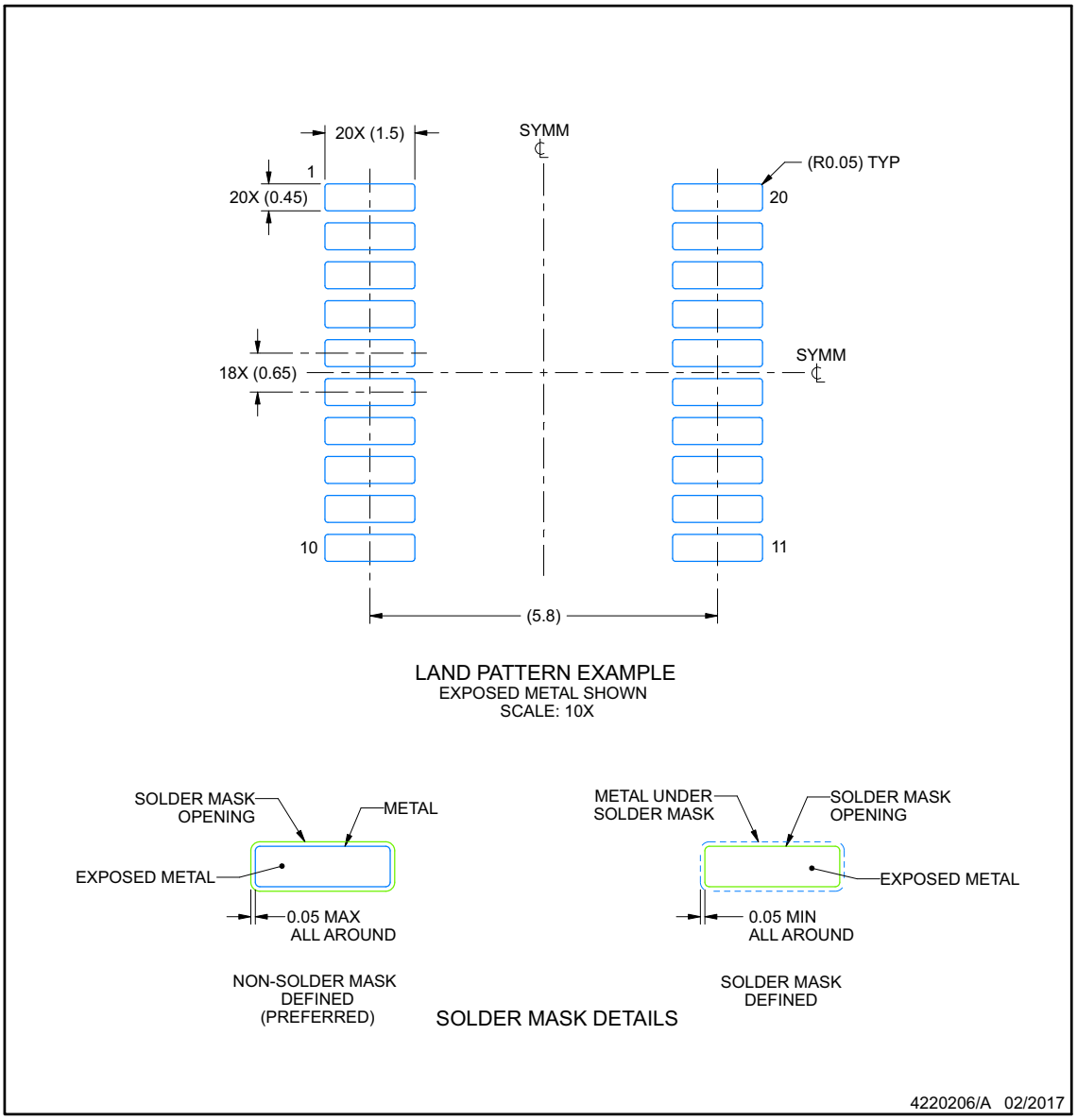
EXAMPLE BOARD LAYOUT

PW0020A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

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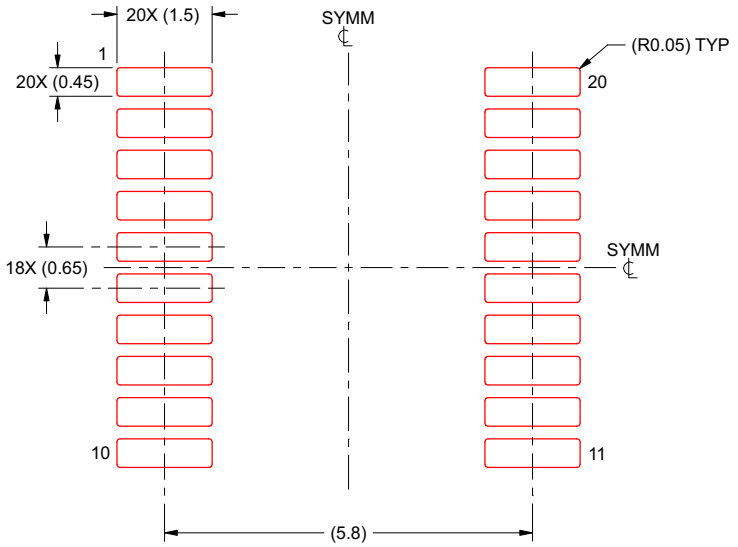
EXAMPLE STENCIL DESIGN

PW0020A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220206/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74LV8T373MPWREP	Active	Production	TSSOP (PW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LV373EP
SN74LV8T373MPWREP.A	Active	Production	TSSOP (PW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LV373EP

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LV8T373-EP :

- Catalog : SN74LV8T373

- Automotive : SN74LV8T373-Q1

NOTE: Qualified Version Definitions:

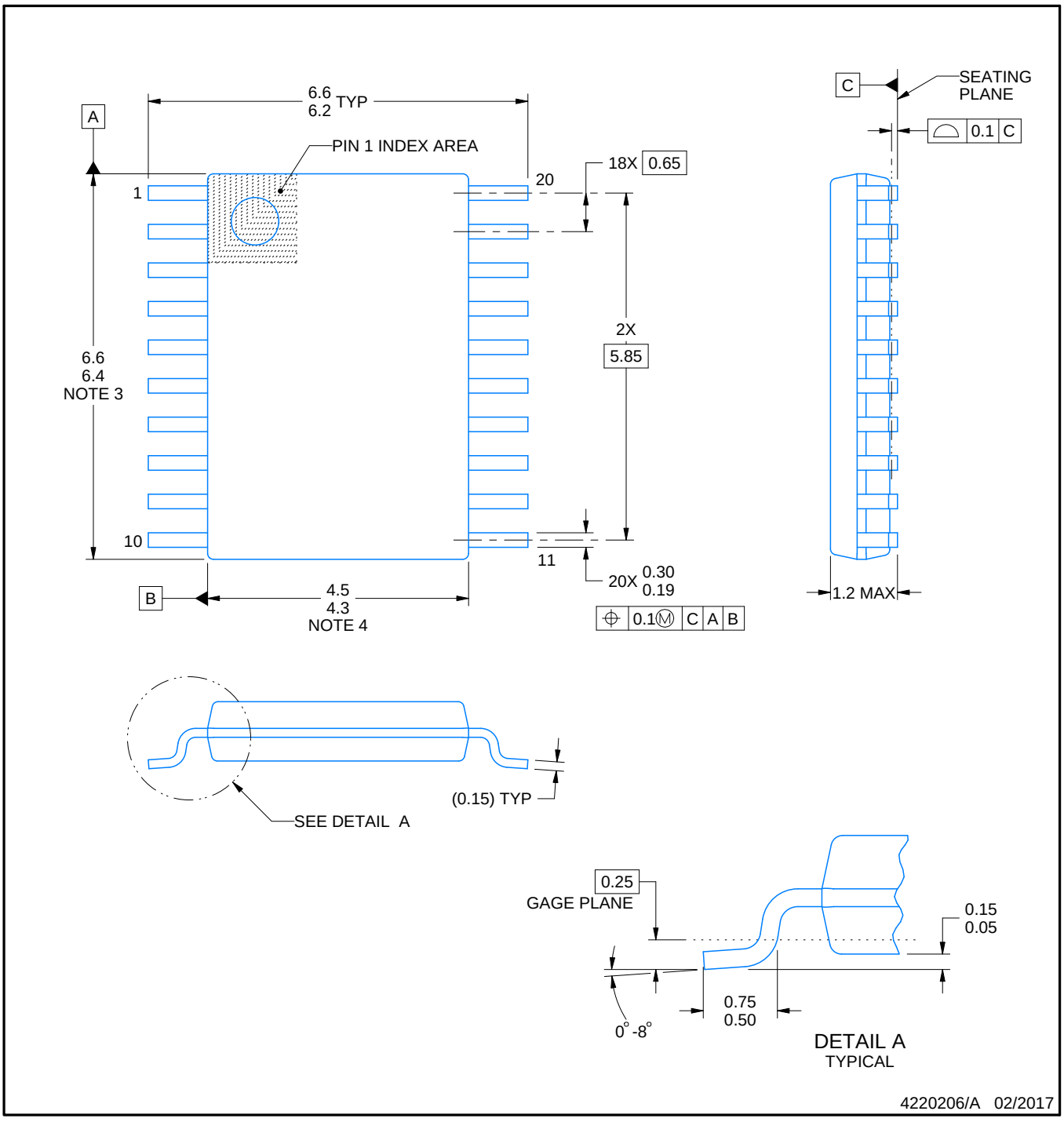
- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE OUTLINE

PW0020A

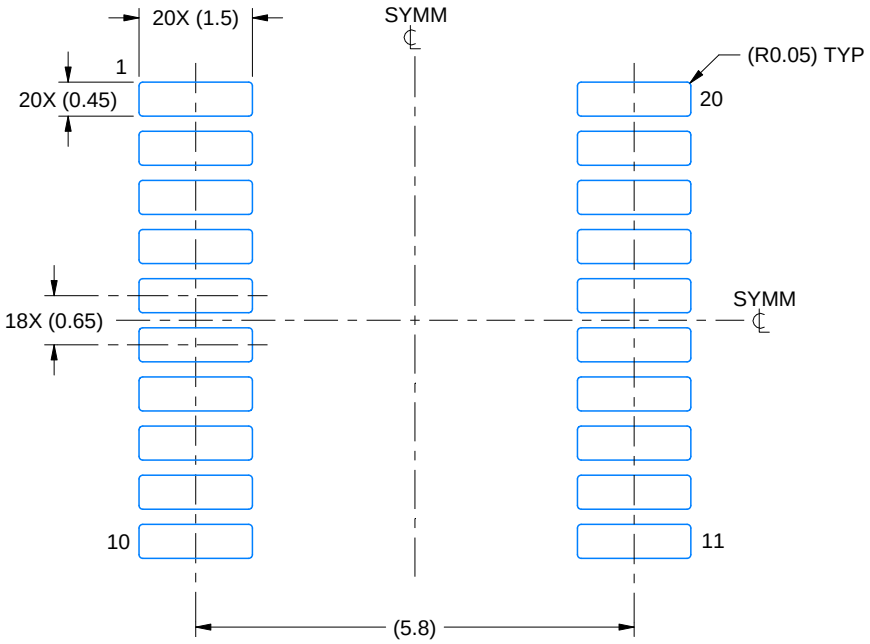
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

NON-SOLDER MASK DEFINED (PREFERRED)

SOLDER MASK DEFINED

SOLDER MASK DETAILS

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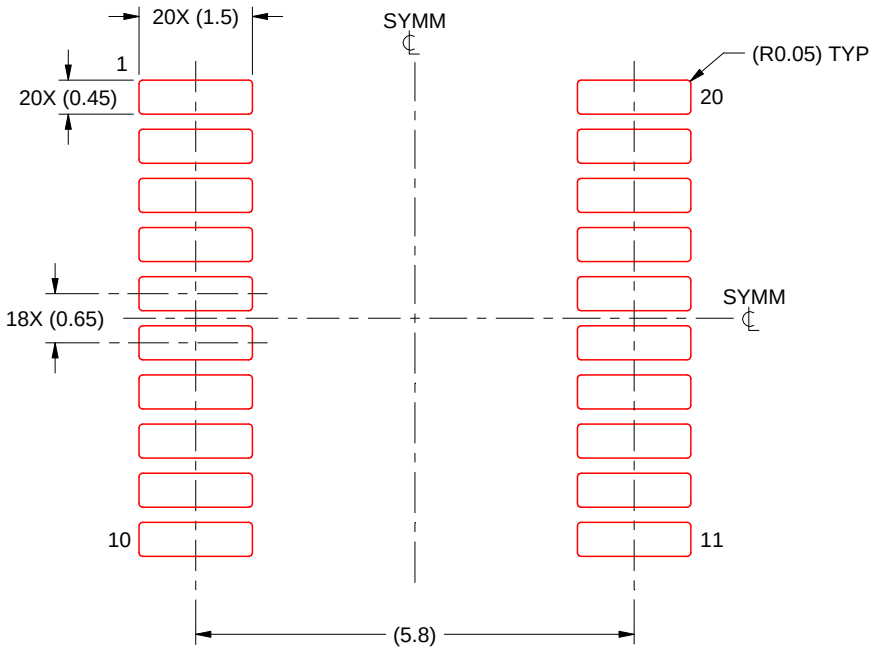
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220206/A 02/2017

NOTES: (continued)

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